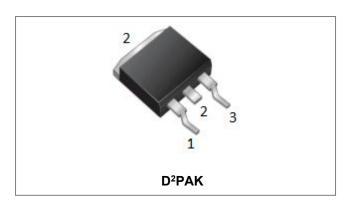


MBRB1545CT

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MBRB1545CT SCHOTTKY RECTIFIER



Features

- 200°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Circuit Diagram

Base common Cathode

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current (Per Device)	IF (AV)	50% duty cycle @Tc=105°C, rectangular wave form	7.5(Per Leg) 15(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	180	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 15A, Pulse, T」 = 25 °C	0.60	0.84	V
(Per Leg) *	V _{F2}	@ 15A, Pulse, T」 = 125 °C	0.57	0.72	V
Reverse Current (Per Leg) *	I _{R1}	$@V_R = rated V_{R_j} T_J = 25 \ ^{\circ}C$	0.03	1.0	mA
	I _{R2}	$@V_R = rated V_{R_j} T_J = 125 \ ^{\circ}C$	15	25	mA
Junction Capacitance(Per Leg)	Ст	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C, f_{SIG} = 1MHz$	300	400	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 µs, duty cycle < 2%

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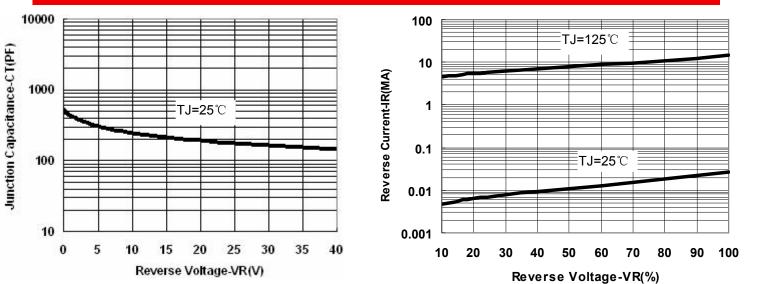
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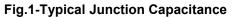
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Thermal-Mechanical Specifications:

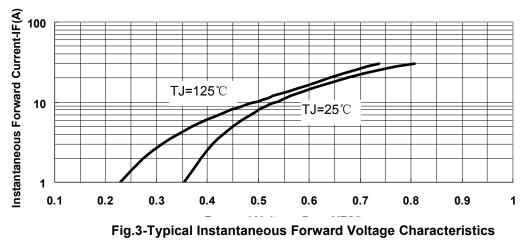
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	V _R ≪80%V _{RRM} V _R ≪50%V _{RRM}	-55 to +150 -55 to +180 -55 to +200	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D ² PAK			

Ratings and Characteristics Curves









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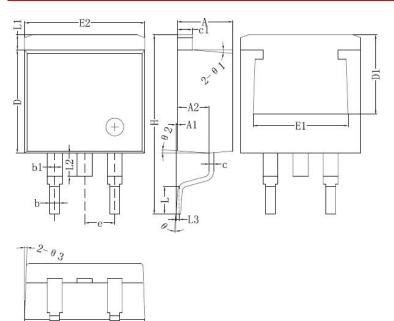


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Mechanical Dimensions D²PAK



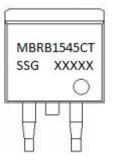
Symbol	Dimensions in millimeter			
	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
c	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4 °		
e3		4 °		

Ordering Information

Device	Package	Shipping
MBRB1545CT	D ² PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type

В

15

45

СТ

YΥ

ww

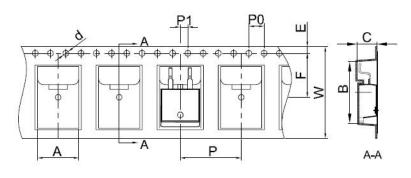
L

SSG

- = Package type = Forward Current (15A)
- = Reverse Voltage(45V)
- = Configuration
- = SSG
- = Year = Week
- = Lot Number

Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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Cautions: Molding resin



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